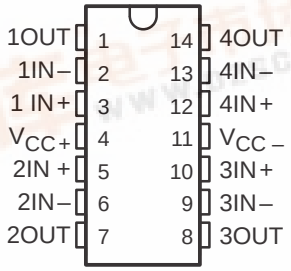
LM148, LM248, LM348
QUADRUPLE OPERATIONAL AMPLIFIERS

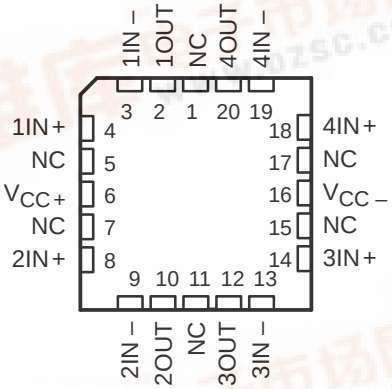
SLOS058B – OCTOBER 1979 – REVISED AUGUST 1996

- μA741 Operating Characteristics
- Low Supply Current Drain . . . 0.6 mA Typ (per amplifier)
- Low Input Offset Voltage
- Low Input Offset Current
- Class AB Output Stage
- Input/Output Overload Protection
- Designed to Be Interchangeable With National LM148, LM248, and LM348

LM148 . . . J PACKAGE
LM248, LM348 . . . D, N, OR PW PACKAGE
(TOP VIEW)



LM148 . . . FK PACKAGE
(TOP VIEW)



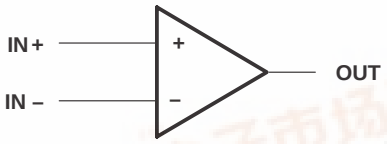
NC – No internal connection

description

The LM148, LM248, and LM348 are quadruple, independent, high-gain, internally compensated operational amplifiers designed to have operating characteristics similar to the μA741. These amplifiers exhibit low supply current drain, and input bias and offset currents that are much less than those of the μA741.

The LM148 is characterized for operation over the full military temperature range of –55°C to 125°C, the LM248 is characterized for operation from –25°C to 85°C, and the LM348 is characterized for operation from 0°C to 70°C.

symbol (each amplifier)



AVAILABLE OPTIONS

T_A	V_{IO}max AT 25°C	PACKAGE				
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	TSSOP (PW)
0°C to 70°C	6 mV	LM348D	—	—	LM348N	LM348PW
–25°C to 85°C	6 mV	LM248D	—	—	LM248N	—
–55°C to 125°C	5 mV	—	LM148FK	LM148J	—	—

The D package is available taped and reeled. Add the suffix R to the device type (e.g., LM348DR).

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		LM148	LM248	LM348	UNIT
Supply voltage, V_{CC+} (see Note 1)		22	18	18	V
Supply voltage, V_{CC-} (see Note 1)		–22	–18	–18	V
Differential input voltage, V_{ID} (see Note 2)		44	36	36	V
Input voltage, V_I (either input, see Notes 1 and 3)		±22	±18	±18	V
Duration of output short circuit (see Note 4)		unlimited	unlimited	unlimited	
Continuous total power dissipation		See Dissipation Rating Table			
Operating free-air temperature range, T_A		–55 to 125	–25 to 85	0 to 70	°C
Storage temperature range		–65 to 150	–65 to 150	–65 to 150	°C
Case temperature for 60 seconds	FK package	260			°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J package	300			°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D, N, or PW package		260	260	°C

NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
2. Differential voltages are at IN+ with respect to IN–.
3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or the value specified in the table, whichever is less.
4. The output may be shorted to ground or either power supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR	DERATE ABOVE T_A	$T_A = 70°C$ POWER RATING	$T_A = 85°C$ POWER RATING	$T_A = 125°C$ POWER RATING
D	900 mW	7.6 mW/°C	32°C	611 mW	497 mW	N/A
FK	900 mW	11.0 mW/°C	68°C	878 mW	713 mW	273 mW
J	900 mW	11.0 mW/°C	68°C	878 mW	713 mW	273 mW
N	900 mW	9.2 mW/°C	52°C	734 mW	596 mW	N/A
PW	700 mW	5.6 mW/°C	N/A	448 mW	N/A	N/A

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V_{CC+}	4	18	V
Supply voltage, V_{CC-}	–4	–18	V

electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = ±15 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS†			LM148			LM248			LM348			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	V_O = 0		25°C		1	5		1	6		1	6	mV
				Full range			6			7.5			7.5	
I_{IO}	Input offset current	V_O = 0		25°C		4	25		4	50		4	50	nA
				Full range			75			125			100	
I_{IB}	Input bias current	V_O = 0		25°C		30	100		30	200		30	200	nA
				Full range			325			500			400	
V_{ICR}	Common-mode input voltage range			Full range	±12			±12			±12			V
V_{OM}	Maximum peak output voltage swing	R_L = 10 kΩ		25°C	±12	±13		±12	±13		±12	±13		V
		R_L ≥ 10 kΩ		Full range	±12			±12			±12			
		R_L = 2 kΩ		25°C	±10	±12		±10	±12		±10	±12		
		R_L ≥ 2 kΩ		Full range	±10			±10			±10			
A_{VD}	Large-signal differential voltage amplification	V_O = ±10 V, R_L = ≥ 2 kΩ		25°C	50	160		25	160		25	160		V/mV
				Full range	25			15			15			
r_i	Input resistance‡			25°C	0.8	2.5		0.8	2.5		0.8	2.5		MΩ
B_1	Unity-gain bandwidth	A_{VD} = 1		25°C		1			1			1		MHz
ϕ_m	Phase margin	A_{VD} = 1		25°C		60°			60°			60°		
CMRR	Common-mode rejection ratio	V_{IC} = V_{ICR}min, V_O = 0		25°C	70	90		70	90		70	90		dB
				Full range	70			70			70			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm}$ = ± 9 V to ± 15 V, V_O = 0		25°C	77	96		77	96		77	96		dB
				Full range	77			77			77			
I_{OS}	Short-circuit output current			25°C		±25			±25			±25		mA
I_{CC}	Supply current (four amplifiers)	No load	V_O = 0	25°C					2.4	4.5		2.4	4.5	mA
			V_O = V_{OM}			2.4	3.6							
V_{O1}/V_{O2}	Crosstalk attenuation	f = 1 Hz to 20 kHz		25°C		120			120			120		dB

† All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range for T_A is −55°C to 125°C for LM148, −25°C to 85°C for LM248, and 0°C to 70°C for LM348.

‡ This parameter is not production tested.

operating characteristics, $V_{CC\pm}$ = ±15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	R_L = 2 kΩ, C_L = 100 pF, See Figure 1		0.5		V/μs

PARAMETER MEASUREMENT INFORMATION

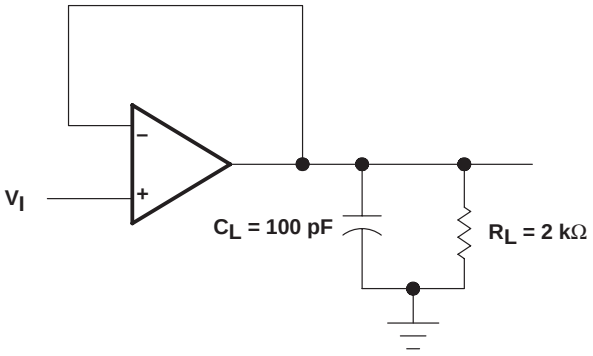


Figure 1. Unity-Gain Amplifier

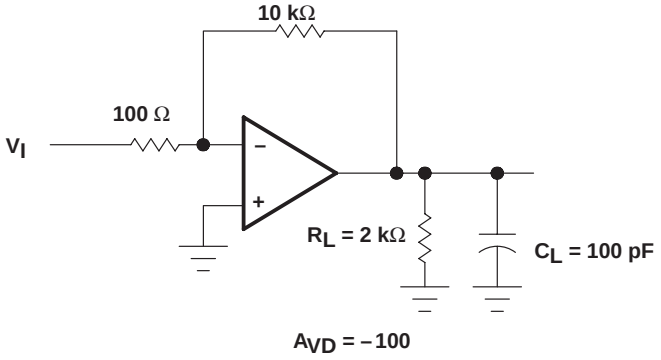


Figure 2. Inverting Amplifier

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